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## Correction: Optical and electrical effects of plasmonic nanoparticles in high-efficiency hybrid solar cells

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Correction for 'Optical and electrical effects of plasmonic nanoparticles in high-efficiency hybrid solar cells' by Wei-Fei Fu *et al.*, *Phys. Chem. Chem. Phys.*, 2013, 15, 17105–17111, DOI: 10.1039/C3CP52723A.

We found that Fig. 4 on page 17108 was not the correct figure for “Current density–voltage ( $J$ – $V$ ) characteristics (a) and the external quantum efficiency (EQE) (b) of the HSCs with different concentrations of Au NPs in PEDOT:PSS layer”; it was the same figure as Fig. 5 by mistake. The correct figure is shown below.

Please note that this Correction does not affect in any way the main conclusions of the paper.

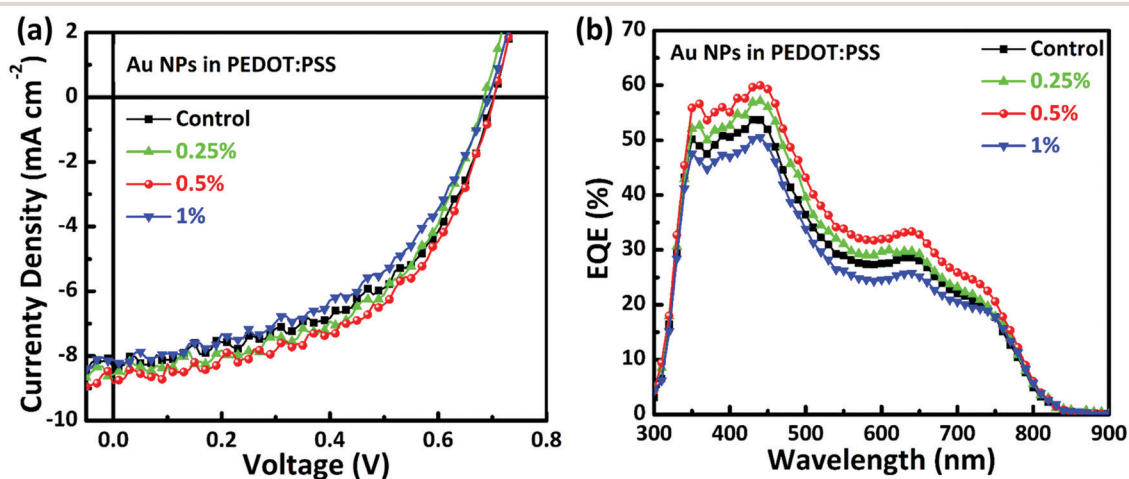


Fig. 4 Current density–voltage ( $J$ – $V$ ) characteristics (a) and the external quantum efficiency (EQE) (b) of the HSCs with different concentrations of Au NPs in the PEDOT:PSS layer.

The Royal Society of Chemistry apologises for these errors and any consequent inconvenience to authors and readers.

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